

74HC4094; 74HCT4094

8-stage shift-and-store bus register

Rev. 5 — 28 June 2012

Product data sheet

1. General description

The 74HC4094; 74HCT4094 are high-speed Si-gate CMOS devices and are pin compatible with the 4094 of the 4000B series. It is specified in compliance with JEDEC standard no. 7A.

The 74HC4094; 74HCT4094 is an 8-stage serial shift register. It has a storage latch associated with each stage for strobing data from the serial input to parallel buffered 3-state outputs QP0 to QP7. The parallel outputs may be connected directly to common bus lines. Data is shifted on positive-going clock transitions. The data in each shift register stage is transferred to the storage register when the strobe (STR) input is HIGH. Data in the storage register appears at the outputs whenever the output enable (OE) signal is HIGH.

Two serial outputs (QS1 and QS2) are available for cascading a number of 74HC4094; 74HCT4094 devices. Serial data is available at QS1 on positive-going clock edges to allow high-speed operation in cascaded systems with a fast clock rise time. The same serial data is available at QS2 on the next negative going clock edge. This is used for cascading 74HC4094; 74HCT4094 devices when the clock has a slow rise time.

2. Features and benefits

- Low-power dissipation
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2 000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and from $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$

3. Applications

- Serial-to-parallel data conversion
- Remote control holding register



4. Ordering information

Table 1. Ordering information

| Type number | Package | | | |
|-------------|-------------------|---------|--|----------|
| | Temperature range | Name | Description | Version |
| 74HC4094N | -40 °C to +125 °C | DIP16 | plastic dual in-line package; 16 leads (300 mil) | SOT38-4 |
| 74HCT4094N | | | | |
| 74HC4094D | -40 °C to +125 °C | SO16 | plastic small outline package; 16 leads; body width 3.9 mm | SOT109-1 |
| 74HCT4094D | | | | |
| 74HC4094DB | -40 °C to +125 °C | SSOP16 | plastic shrink small outline package; 16 leads; body width 5.3 mm | SOT338-1 |
| 74HCT4094DB | | | | |
| 74HC4094PW | -40 °C to +125 °C | TSSOP16 | plastic thin shrink small outline package; 16 leads; body width 4.4 mm | SOT403-1 |

5. Functional diagram

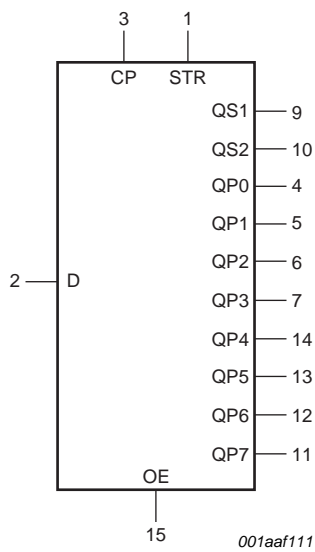


Fig 1. Functional diagram

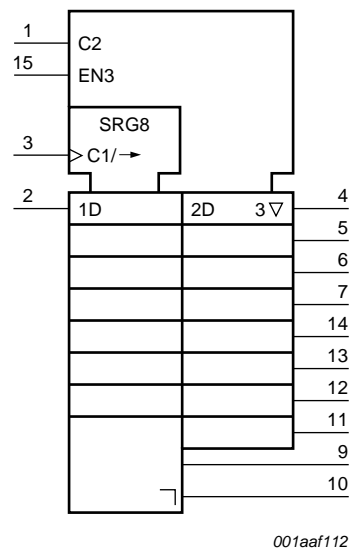


Fig 2. Logic symbol

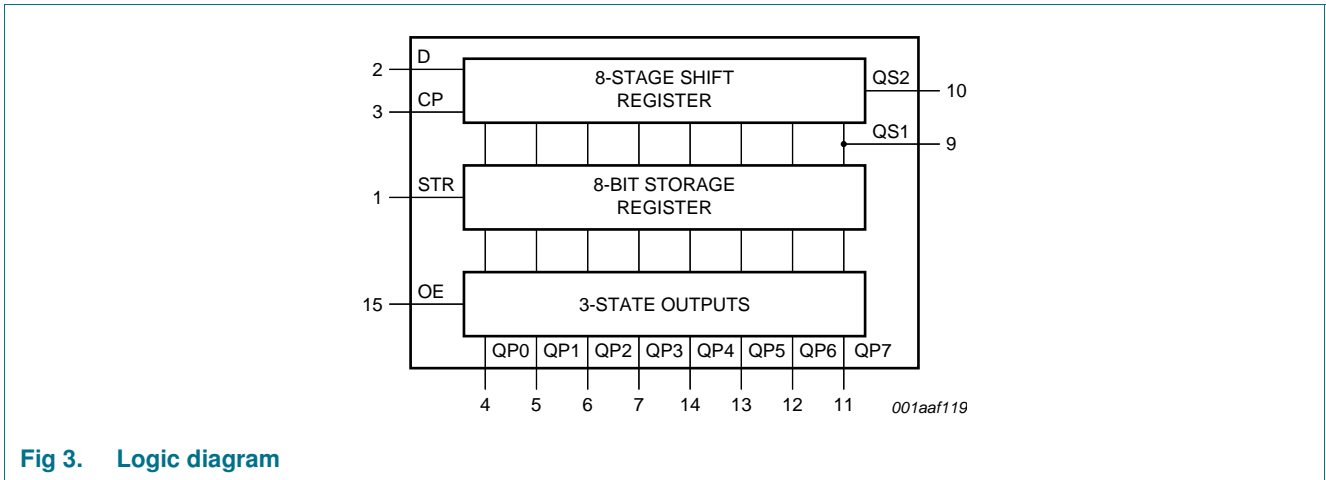


Fig 3. Logic diagram

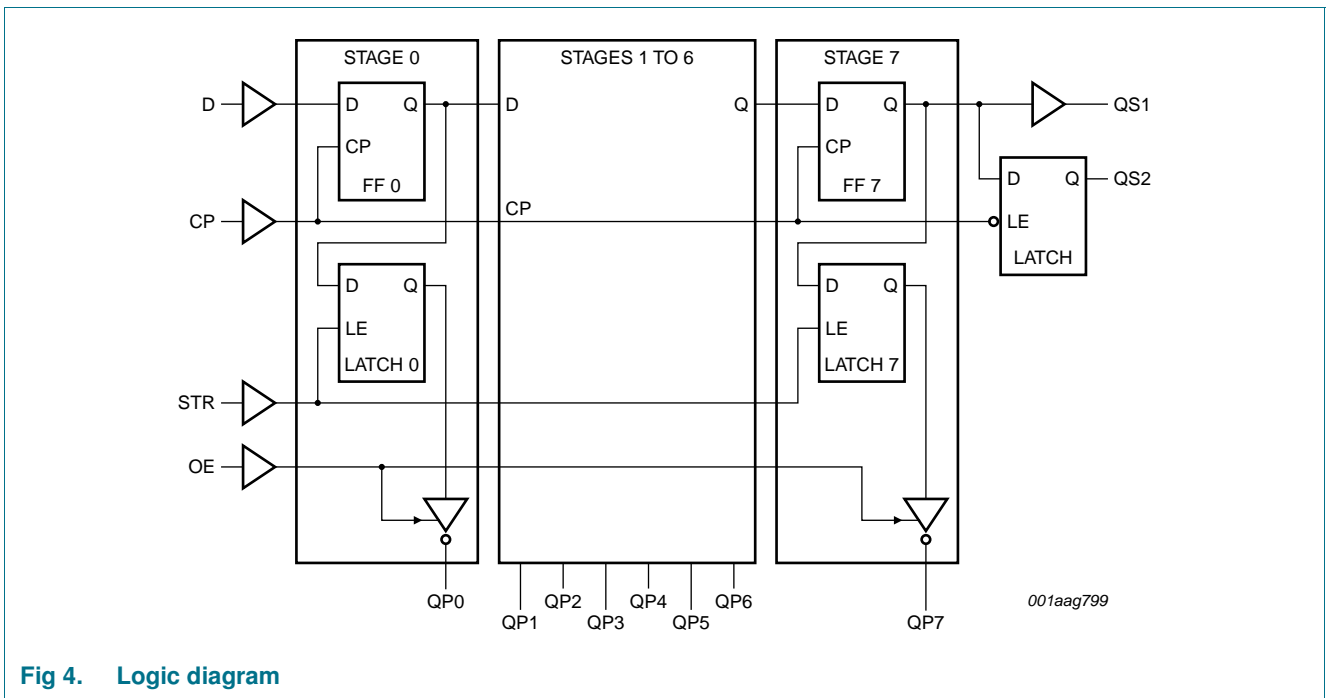


Fig 4. Logic diagram

6. Pinning information

6.1 Pinning

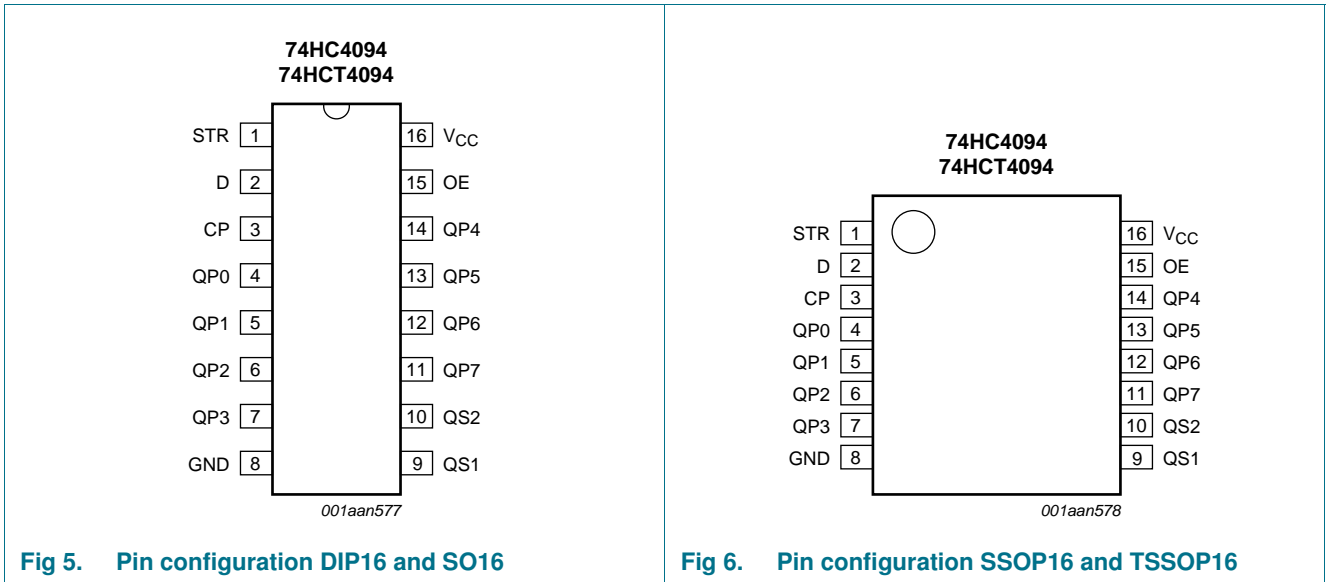


Fig 5. Pin configuration DIP16 and SO16

Fig 6. Pin configuration SSOP16 and TSSOP16

6.2 Pin description

Table 2. Pin description

| Symbol | Pin | Description |
|-----------------|----------------------------|-----------------------|
| STR | 1 | strobe input |
| D | 2 | data input |
| CP | 3 | clock input |
| QP0 to QP7 | 4, 5, 6, 7, 14, 13, 12, 11 | parallel output |
| V _{SS} | 8 | ground supply voltage |
| QS1, QS2 | 9, 10 | serial output |
| OE | 15 | output enable input |
| V _{DD} | 16 | supply voltage |

7. Functional description

Table 3. Function table^[1]

| Inputs | | | | Parallel outputs | | Serial outputs | |
|--------|----|-----|---|------------------|---------|----------------|-----|
| CP | OE | STR | D | QP0 | QPn | QS1 | QS2 |
| ↑ | L | X | X | Z | Z | Q6S | NC |
| ↓ | L | X | X | Z | Z | NC | Q7S |
| ↑ | H | L | X | NC | NC | Q6S | NC |
| ↑ | H | H | L | L | QPn - 1 | Q6S | NC |
| ↑ | H | H | H | H | QPn - 1 | Q6S | NC |
| ↓ | H | H | H | NC | NC | NC | Q7S |

- [1] At the positive clock edge, the information in the 7th register stage is transferred to the 8th register stage and the QSn outputs.
 H = HIGH voltage level; L = LOW voltage level; X = don't care;
 ↑ = positive-going transition; ↓ = negative-going transition;
 Z = HIGH-impedance OFF-state; NC = no change;
 Q6S = the data in register stage 6 before the LOW to HIGH clock transition;
 Q7S = the data in register stage 7 before the HIGH to LOW clock transition.

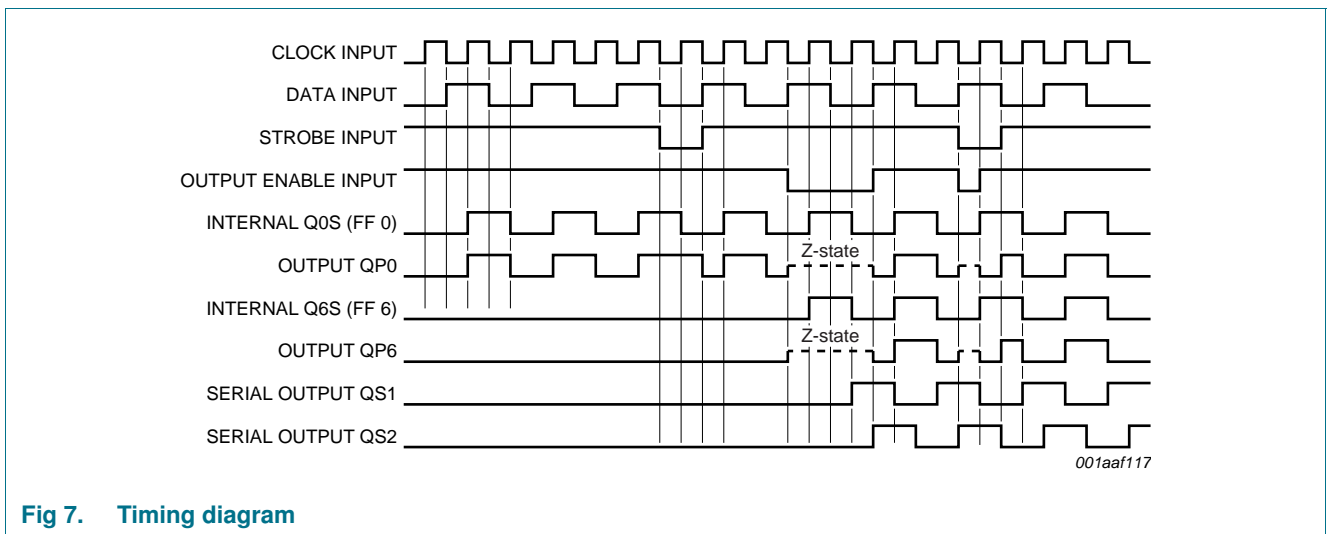


Fig 7. Timing diagram

8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit | |
|-----------|-------------------------|--|------|----------|------|----|
| V_{CC} | supply voltage | | -0.5 | +7 | V | |
| I_{IK} | input clamping current | $V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$ | - | ± 20 | mA | |
| I_{OK} | output clamping current | $V_O < -0.5\text{ V}$ or $V_O > V_{CC} + 0.5\text{ V}$ | - | ± 20 | mA | |
| I_O | output current | $V_O = -0.5\text{ V}$ to $(V_{CC} + 0.5\text{ V})$ | - | ± 25 | mA | |
| I_{CC} | supply current | | - | +50 | mA | |
| I_{GND} | ground current | | - | -50 | mA | |
| T_{stg} | storage temperature | | -65 | +150 | °C | |
| P_{tot} | total power dissipation | DIP16 package | [1] | - | 750 | mW |
| | | SO16, SSOP16 and TSSOP16 packages | [2] | - | 500 | mW |

[1] For DIP16 package: P_{tot} derates linearly with 12 mW/K above 70 °C.

[2] For SO16: P_{tot} derates linearly with 8 mW/K above 70 °C.

For SSOP16 and TSSOP16 packages: P_{tot} derates linearly with 5.5 mW/K above 60 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

| Symbol | Parameter | Conditions | 74HC4094 | | | 74HCT4094 | | | Unit |
|---------------------|-------------------------------------|-------------------------|----------|------|----------|-----------|------|----------|------|
| | | | Min | Typ | Max | Min | Typ | Max | |
| V_{CC} | supply voltage | | 2.0 | 5.0 | 6.0 | 4.5 | 5.0 | 5.5 | V |
| V_I | input voltage | | 0 | - | V_{CC} | 0 | - | V_{CC} | V |
| V_O | output voltage | | 0 | - | V_{CC} | 0 | - | V_{CC} | V |
| T_{amb} | ambient temperature | | -40 | +25 | +125 | -40 | +25 | +125 | °C |
| $\Delta t/\Delta V$ | input transition rise and fall rate | $V_{CC} = 2.0\text{ V}$ | - | - | 625 | - | - | - | ns/V |
| | | $V_{CC} = 4.5\text{ V}$ | - | 1.67 | 139 | - | 1.67 | 139 | ns/V |
| | | $V_{CC} = 6.0\text{ V}$ | - | - | 83 | - | - | - | ns/V |

10. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | 25 °C | | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit | | | | |
|-----------------|---------------------------|---|--------------------------|--|-------------------|--|------|-------------------|------|------|-------|----|-----|----|
| | | | Min | Typ | Max | Min | Max | Min | Max | | | | | |
| 74HC4094 | | | | | | | | | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 2.0 V | 1.5 | 1.2 | - | 1.5 | - | 1.5 | - | V | | | | |
| | | V _{CC} = 4.5 V | 3.15 | 2.4 | - | 3.15 | - | 3.15 | - | V | | | | |
| | | V _{CC} = 6.0 V | 4.2 | 3.2 | - | 4.2 | - | 4.2 | - | V | | | | |
| V _{IL} | LOW-level input voltage | V _{CC} = 2.0 V | - | 0.8 | 0.5 | - | 0.5 | - | 0.5 | V | | | | |
| | | V _{CC} = 4.5 V | - | 2.1 | 1.35 | - | 1.35 | - | 1.35 | V | | | | |
| | | V _{CC} = 6.0 V | - | 2.8 | 1.8 | - | 1.8 | - | 1.8 | V | | | | |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | | | | | | | | | |
| | | I _O = -20 μA; V _{CC} = 2.0 V | 1.9 | 2.0 | - | 1.9 | - | 1.9 | - | V | | | | |
| | | I _O = -20 μA; V _{CC} = 4.5 V | 4.4 | 4.5 | - | 4.4 | - | 4.4 | - | V | | | | |
| | | I _O = -20 μA; V _{CC} = 6.0 V | 5.9 | 6.0 | - | 5.9 | - | 5.9 | - | V | | | | |
| | | I _O = -4.0 mA; V _{CC} = 4.5 V | 3.98 | 4.32 | - | 3.84 | - | 3.7 | - | V | | | | |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | | | | | | | | | |
| | | I _O = 20 μA; V _{CC} = 2.0 V | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V | | | | |
| | | I _O = 20 μA; V _{CC} = 4.5 V | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V | | | | |
| | | I _O = 20 μA; V _{CC} = 6.0 V | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V | | | | |
| | | I _O = 4.0 mA; V _{CC} = 4.5 V | - | 0.15 | 0.26 | - | 0.33 | - | 0.4 | V | | | | |
| I _I | input leakage current | V _I = V _{CC} or GND; V _{CC} = 6.0 V | - | - | ±0.1 | - | ±1.0 | - | ±1.0 | μA | | | | |
| | | I _{OZ} | OFF-state output current | V _I = V _{IH} or V _{IL} ; V _O = V _{CC} or GND; V _{CC} = 6.0 V | - | - | ±0.5 | - | ±5.0 | - | ±10.0 | μA | | |
| | | | | I _{CC} | supply current | V _I = V _{CC} or GND; I _O = 0 A; V _{CC} = 6.0 V | - | - | 8.0 | - | 80 | - | 160 | μA |
| | | | | C _I | input capacitance | | - | 3.5 | - | | | | pF | |
| | | | | 74HCT4094 | | | | | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 4.5 V to 5.5 V | 2.0 | 1.6 | - | 2.0 | - | 2.0 | - | V | | | | |
| V _{IL} | LOW-level input voltage | V _{CC} = 4.5 V to 5.5 V | - | 1.2 | 0.8 | - | 0.8 | - | 0.8 | V | | | | |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} ; V _{CC} = 4.5 V | | | | | | | | | | | | |
| | | I _O = -20 μA | 4.4 | 4.5 | - | 4.4 | - | 4.4 | - | V | | | | |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} ; V _{CC} = 4.5 V | | | | | | | | | | | | |
| | | I _O = -4.0 mA | 3.98 | 4.32 | - | 3.84 | - | 3.7 | - | V | | | | |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} ; V _{CC} = 4.5 V | | | | | | | | | | | | |
| | | I _O = 20 μA | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V | | | | |
| | | I _O = 4.0 mA | - | 0.15 | 0.26 | - | 0.33 | - | 0.4 | V | | | | |

Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | 25 °C | | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit | |
|-----------------|---------------------------|---|--------------------------|-----|------|------------------|------|-------------------|------|------|----|
| | | | Min | Typ | Max | Min | Max | Min | Max | | |
| I_I | input leakage current | $V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V | - | - | ±0.1 | - | ±1.0 | - | ±1.0 | µA | |
| I_{OZ} | OFF-state output current | $V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 5.5$ V; $V_O = V_{CC}$ or GND per input pin; other inputs at V_{CC} or GND; $I_O = 0$ A | - | - | ±0.5 | - | ±5.0 | - | ±10 | µA | |
| I_{CC} | supply current | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V | - | - | 8.0 | - | 80 | - | 160 | µA | |
| ΔI_{CC} | additional supply current | $V_I = V_{CC} - 2.1$ V; other inputs at V_{CC} or GND; $V_{CC} = 4.5$ V to 5.5 V; $I_O = 0$ A | per input pin; STR input | - | 100 | 360 | - | 450 | - | 490 | µA |
| | | | per input pin; OE input | - | 150 | 540 | - | 675 | - | 735 | µA |
| | | | per input pin; CP input | - | 150 | 540 | - | 675 | - | 735 | µA |
| | | | per input pin; D input | - | 40 | 144 | - | 180 | - | 196 | µA |
| C_I | input capacitance | | - | 3.5 | - | | | | | pF | |

11. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); $C_L = 50$ pF unless otherwise specified; for test circuit see [Figure 12](#).

| Symbol | Parameter | Conditions | 25 °C | | | −40 °C to +85 °C | | −40 °C to +125 °C | | Unit |
|-------------------------------|-------------------|--|-------|-----|-----|------------------|-----|-------------------|-----|------|
| | | | Min | Typ | Max | Min | Max | Min | Max | |
| 74HC4094 | | | | | | | | | | |
| t_{pd} | propagation delay | CP to QS1; see Figure 8 ^[1] | | | | | | | | |
| | | $V_{CC} = 2.0$ V | - | 50 | 150 | - | 190 | - | 225 | ns |
| | | $V_{CC} = 4.5$ V | - | 18 | 30 | - | 38 | - | 45 | ns |
| | | $V_{CC} = 5$ V; $C_L = 15$ pF | - | 15 | - | - | - | - | - | ns |
| | | $V_{CC} = 6.0$ V | - | 14 | 26 | - | 33 | - | 38 | ns |
| | | CP to QS2; see Figure 8 ^[1] | | | | | | | | |
| | | $V_{CC} = 2.0$ V | - | 44 | 135 | - | 170 | - | 205 | ns |
| | | $V_{CC} = 4.5$ V | - | 16 | 27 | - | 34 | - | 41 | ns |
| | | $V_{CC} = 5$ V; $C_L = 15$ pF | - | 13 | - | - | - | - | - | ns |
| | | $V_{CC} = 6.0$ V | - | 13 | 23 | - | 29 | - | 35 | ns |
| | | CP to QPn; see Figure 8 ^[1] | | | | | | | | |
| | | $V_{CC} = 2.0$ V | - | 63 | 195 | - | 245 | - | 295 | ns |
| | | $V_{CC} = 4.5$ V | - | 23 | 39 | - | 49 | - | 59 | ns |
| | | $V_{CC} = 5$ V; $C_L = 15$ pF | - | 20 | - | - | - | - | - | ns |
| | | $V_{CC} = 6.0$ V | - | 18 | 33 | - | 42 | - | 50 | ns |
| | | STR to QPn; see Figure 9 ^[1] | | | | | | | | |
| $V_{CC} = 2.0$ V | - | 58 | 180 | - | 225 | - | 270 | ns | | |
| $V_{CC} = 4.5$ V | - | 21 | 36 | - | 45 | - | 54 | ns | | |
| $V_{CC} = 5$ V; $C_L = 15$ pF | - | 18 | - | - | - | - | - | ns | | |
| $V_{CC} = 6.0$ V | - | 17 | 31 | - | 38 | - | 46 | ns | | |
| t_{en} | enable time | OE to QPn; see Figure 11 ^[2] | | | | | | | | |
| | | $V_{CC} = 2.0$ V | - | 55 | 175 | - | 220 | - | 265 | ns |
| | | $V_{CC} = 4.5$ V | - | 20 | 35 | - | 44 | - | 53 | ns |
| | | $V_{CC} = 6.0$ V | - | 16 | 30 | - | 37 | - | 45 | ns |
| t_{dis} | disable time | OE to QPn; see Figure 11 ^[3] | | | | | | | | |
| | | $V_{CC} = 2.0$ V | - | 41 | 125 | - | 155 | - | 190 | ns |
| | | $V_{CC} = 4.5$ V | - | 15 | 25 | - | 31 | - | 38 | ns |
| | | $V_{CC} = 6.0$ V | - | 12 | 21 | - | 26 | - | 32 | ns |
| t_t | transition time | QPn and QSn; see Figure 8 ^[4] | | | | | | | | |
| | | $V_{CC} = 2.0$ V | - | 19 | 75 | - | 95 | - | 110 | ns |
| | | $V_{CC} = 4.5$ V | - | 7 | 15 | - | 19 | - | 22 | ns |
| | | $V_{CC} = 6.0$ V | - | 6 | 13 | - | 16 | - | 19 | ns |

Table 7. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); $C_L = 50$ pF unless otherwise specified; for test circuit see [Figure 12](#).

| Symbol | Parameter | Conditions | 25 °C | | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit | |
|-----------|-------------------------------|---|-------------------|-----|-----|------------------|-----|-------------------|-----|------|--|
| | | | Min | Typ | Max | Min | Max | Min | Max | | |
| t_w | pulse width | CP HIGH or LOW; see Figure 8 | | | | | | | | | |
| | | $V_{CC} = 2.0$ V | 80 | 14 | - | 100 | - | 120 | - | ns | |
| | | $V_{CC} = 4.5$ V | 16 | 5 | - | 20 | - | 24 | - | ns | |
| | | $V_{CC} = 6.0$ V | 14 | 4 | - | 17 | - | 20 | - | ns | |
| | | STR HIGH; see Figure 9 | | | | | | | | | |
| | | $V_{CC} = 2.0$ V | 80 | 14 | - | 100 | - | 120 | - | ns | |
| t_{su} | set-up time | D to CP; see Figure 10 | | | | | | | | | |
| | | $V_{CC} = 2.0$ V | 50 | 14 | - | 65 | - | 75 | - | ns | |
| | | $V_{CC} = 4.5$ V | 10 | 5 | - | 13 | - | 15 | - | ns | |
| | | $V_{CC} = 6.0$ V | 9 | 4 | - | 11 | - | 13 | - | ns | |
| | | CP to STR; see Figure 9 | | | | | | | | | |
| | | $V_{CC} = 2.0$ V | 100 | 28 | - | 125 | - | 150 | - | ns | |
| t_h | hold time | D to CP; see Figure 10 | | | | | | | | | |
| | | $V_{CC} = 2.0$ V | 3 | -6 | - | 3 | - | 3 | - | ns | |
| | | $V_{CC} = 4.5$ V | 3 | -2 | - | 3 | - | 3 | - | ns | |
| | | $V_{CC} = 6.0$ V | 3 | -2 | - | 3 | - | 3 | - | ns | |
| | | CP to STR; see Figure 9 | | | | | | | | | |
| | | $V_{CC} = 2.0$ V | 0 | -14 | - | 0 | - | 0 | - | ns | |
| f_{max} | maximum frequency | CP; see Figure 8 | | | | | | | | | |
| | | $V_{CC} = 2.0$ V | 6.0 | 28 | - | 4.8 | - | 4.0 | - | MHz | |
| | | $V_{CC} = 4.5$ V | 30 | 87 | - | 24 | - | 20 | - | MHz | |
| | | $V_{CC} = 5$ V; $C_L = 15$ pF | - | 95 | - | - | - | - | - | MHz | |
| C_{PD} | power dissipation capacitance | $V_{CC} = 6.0$ V | 35 | 103 | - | 28 | - | 24 | - | MHz | |
| | | $C_L = 50$ pF; $f = 1$ MHz; $V_1 = \text{GND to } V_{CC}$ | 5 | - | 83 | - | - | - | - | pF | |

Table 7. Dynamic characteristics ...continued

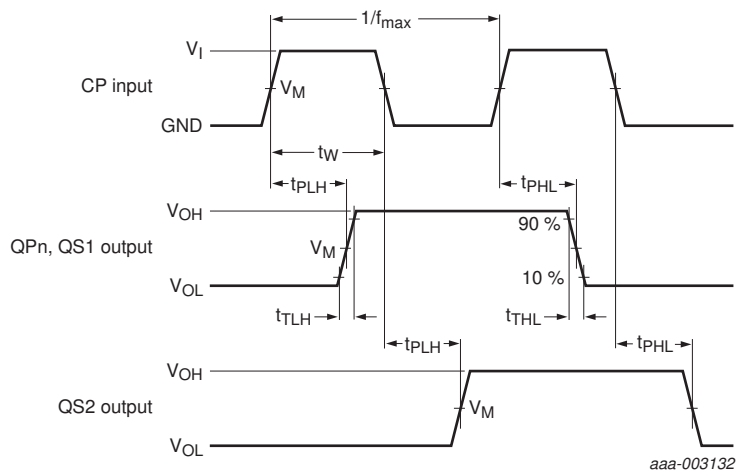
Voltages are referenced to GND (ground = 0 V); $C_L = 50$ pF unless otherwise specified; for test circuit see [Figure 12](#).

| Symbol | Parameter | Conditions | 25 °C | | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit |
|------------------|-------------------------------|---|-------|-----|-----|------------------|-----|-------------------|-----|------|
| | | | Min | Typ | Max | Min | Max | Min | Max | |
| 74HCT4094 | | | | | | | | | | |
| t_{pd} | propagation delay | CP to QS1; see Figure 8 [1] | | | | | | | | |
| | | $V_{CC} = 4.5$ V | - | 23 | 39 | - | 49 | - | 59 | ns |
| | | $V_{CC} = 5$ V; $C_L = 15$ pF | - | 19 | - | - | - | - | - | ns |
| | | CP to QS2; see Figure 8 [1] | | | | | | | | |
| | | $V_{CC} = 4.5$ V | - | 21 | 36 | - | 45 | - | 54 | ns |
| | | $V_{CC} = 5$ V; $C_L = 15$ pF | - | 18 | - | - | - | - | - | ns |
| | | CP to QPn; see Figure 8 [1] | | | | | | | | |
| | | $V_{CC} = 4.5$ V | - | 25 | 43 | - | 54 | - | 65 | ns |
| | | $V_{CC} = 5$ V; $C_L = 15$ pF | - | 21 | - | - | - | - | - | ns |
| t_{en} | enable time | STR to QPn; see Figure 9 [1] | | | | | | | | |
| | | $V_{CC} = 4.5$ V | - | 22 | 39 | - | 49 | - | 59 | ns |
| | | $V_{CC} = 5$ V; $C_L = 15$ pF | - | 19 | - | - | - | - | - | ns |
| t_{dis} | disable time | OE to QPn; see Figure 11 [2] | | | | | | | | |
| | | $V_{CC} = 4.5$ V | - | 20 | 35 | - | 44 | - | 53 | ns |
| t_t | transition time | OE to QPn; see Figure 11 [3] | | | | | | | | |
| | | $V_{CC} = 4.5$ V | - | 21 | 35 | - | 44 | - | 53 | ns |
| t_w | pulse width | QPn and QSn; see Figure 8 [4] | | | | | | | | |
| | | $V_{CC} = 4.5$ V | - | 7 | 15 | - | 19 | - | 22 | ns |
| | | CP HIGH or LOW; see Figure 8 | | | | | | | | |
| t_{su} | set-up time | STR HIGH; see Figure 9 | | | | | | | | |
| | | $V_{CC} = 4.5$ V | 16 | 7 | - | 20 | - | 24 | - | ns |
| t_{su} | set-up time | Dn to CP; see Figure 10 | | | | | | | | |
| | | $V_{CC} = 4.5$ V | 16 | 5 | - | 20 | - | 24 | - | ns |
| | | CP to STR; see Figure 9 | | | | | | | | |
| t_h | hold time | $V_{CC} = 4.5$ V | 16 | 9 | - | 25 | - | 30 | - | ns |
| | | Dn to CP; see Figure 10 | | | | | | | | |
| | | $V_{CC} = 4.5$ V | 4 | 0 | - | 4 | - | 4 | - | ns |
| f_{max} | maximum frequency | CP to STR; see Figure 9 | | | | | | | | |
| | | $V_{CC} = 4.5$ V | 0 | -4 | - | 0 | - | 0 | - | ns |
| | | CP; see Figure 8 | | | | | | | | |
| C_{PD} | power dissipation capacitance | $V_{CC} = 4.5$ V | 30 | 80 | - | 24 | - | 20 | - | MHz |
| | | $V_{CC} = 5$ V; $C_L = 15$ pF | - | 86 | - | - | - | - | - | MHz |
| C_{PD} | power dissipation capacitance | $C_L = 50$ pF; $f = 1$ MHz; $V_I = GND$ to V_{CC} | [5] | 92 | - | - | - | - | - | pF |

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

- [2] t_{en} is the same as t_{PZH} and t_{PZL} .
- [3] t_{dis} is the same as t_{PLZ} and t_{PHZ} .
- [4] t_i is the same as t_{THL} and t_{TLH} .
- [5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o)$ where:
 f_i = input frequency in MHz;
 f_o = output frequency in MHz;
 C_L = output load capacitance in pF;
 V_{CC} = supply voltage in V;
 N = number of inputs switching;
 $\sum(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

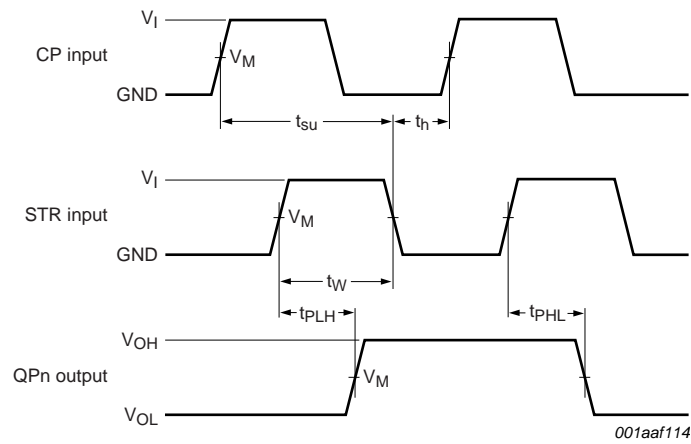
12. Waveforms



Measurement points are given in [Table 8](#).

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

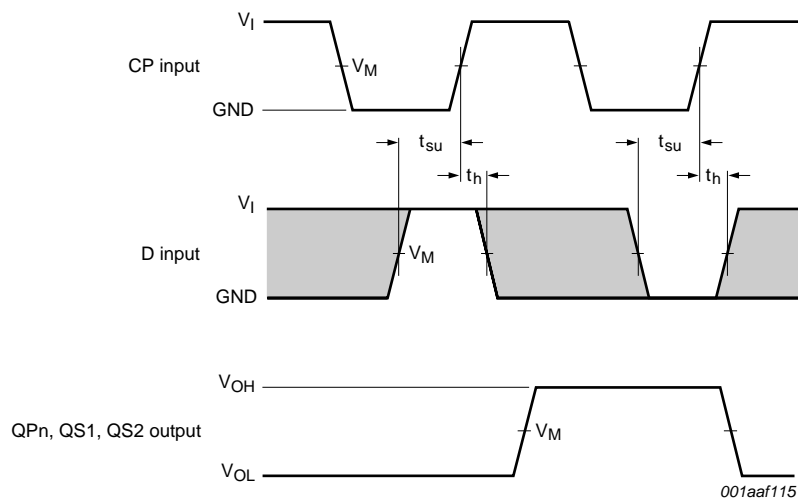
Fig 8. Propagation delay input (CP) to output (QPn, QS1, QS2), output transition time, clock input (CP) pulse width and the maximum frequency (CP)



Measurement points are given in [Table 8](#).

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

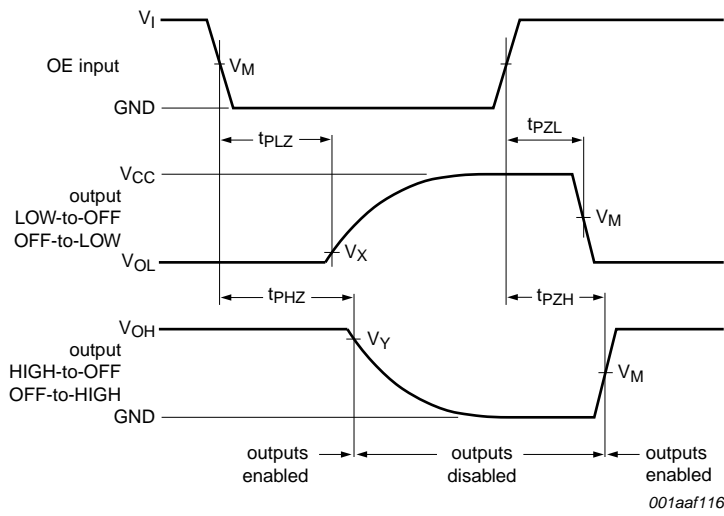
Fig 9. Propagation delay strobe input (STR) to output (QPn), strobe input (STR) pulse width and the clock set-up and hold times for strobe input



Measurement points are given in [Table 8](#).

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 10. The data input (D) to clock input (CP) set-up times and clock input (CP) to data input (D) hold times



Measurement points are given in [Table 8](#).
 V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 11. Enable and disable times

Table 8. Measurement points

| Type | Input | Output | | |
|-----------|-------------|-------------|-------------|-------------|
| | V_M | V_M | V_X | V_Y |
| 74HC4094 | $0.5V_{CC}$ | $0.5V_{CC}$ | $0.1V_{OH}$ | $0.9V_{OH}$ |
| 74HCT4094 | 1.3 V | 1.3 V | $0.1V_{OH}$ | $0.9V_{OH}$ |

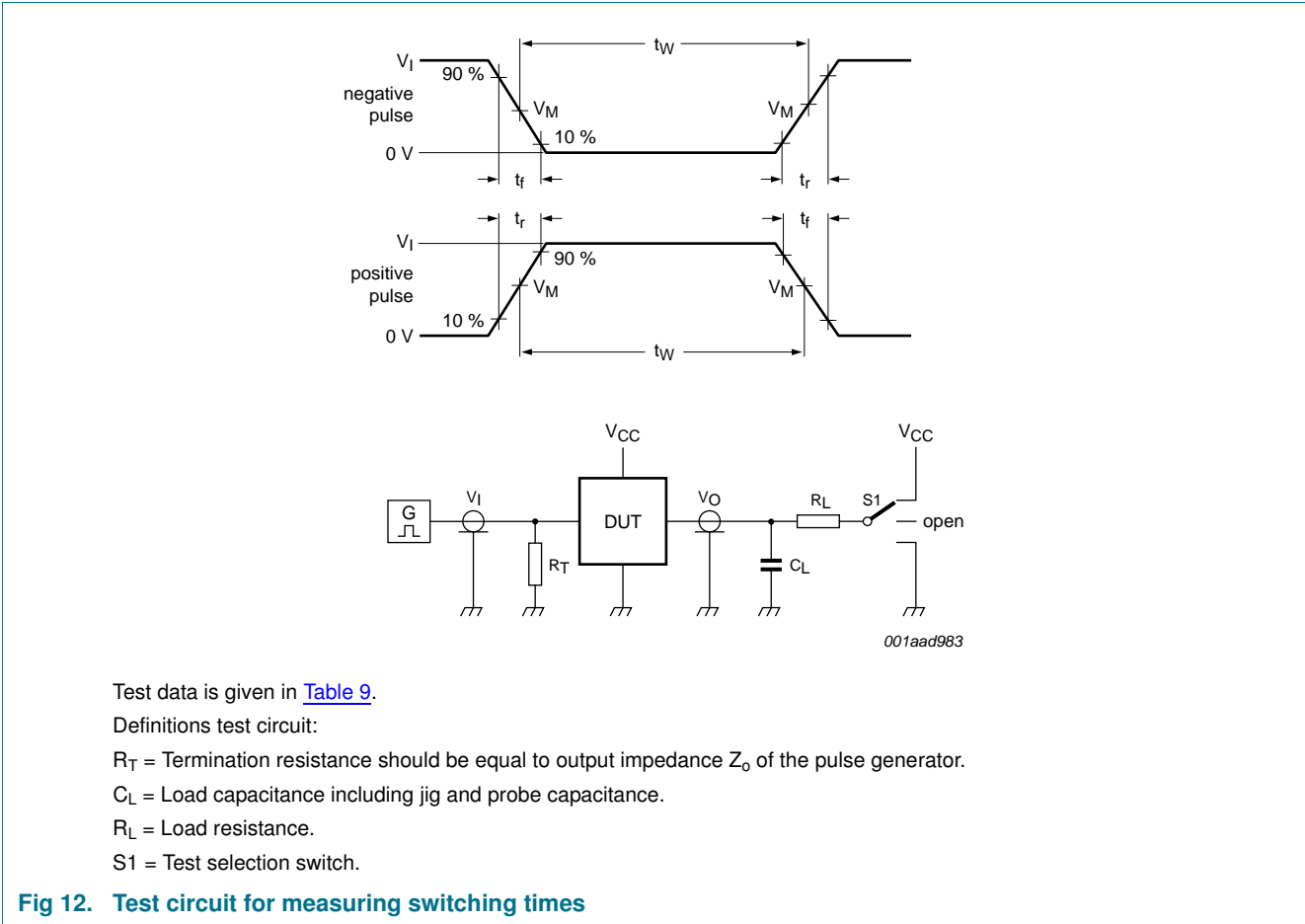


Table 9. Test data

| Type | Input | | Load | | S1 position | | |
|-----------|----------|------------|--------------|--------------|--------------------|--------------------|--------------------|
| | V_I | t_r, t_f | C_L | R_L | t_{PHL}, t_{PLH} | t_{PZH}, t_{PHZ} | t_{PZL}, t_{PLZ} |
| 74HC4094 | V_{CC} | 6 ns | 15 pF, 50 pF | 1 k Ω | open | GND | V_{CC} |
| 74HCT4094 | 3 V | 6 ns | 15 pF, 50 pF | 1 k Ω | open | GND | V_{CC} |

13. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4

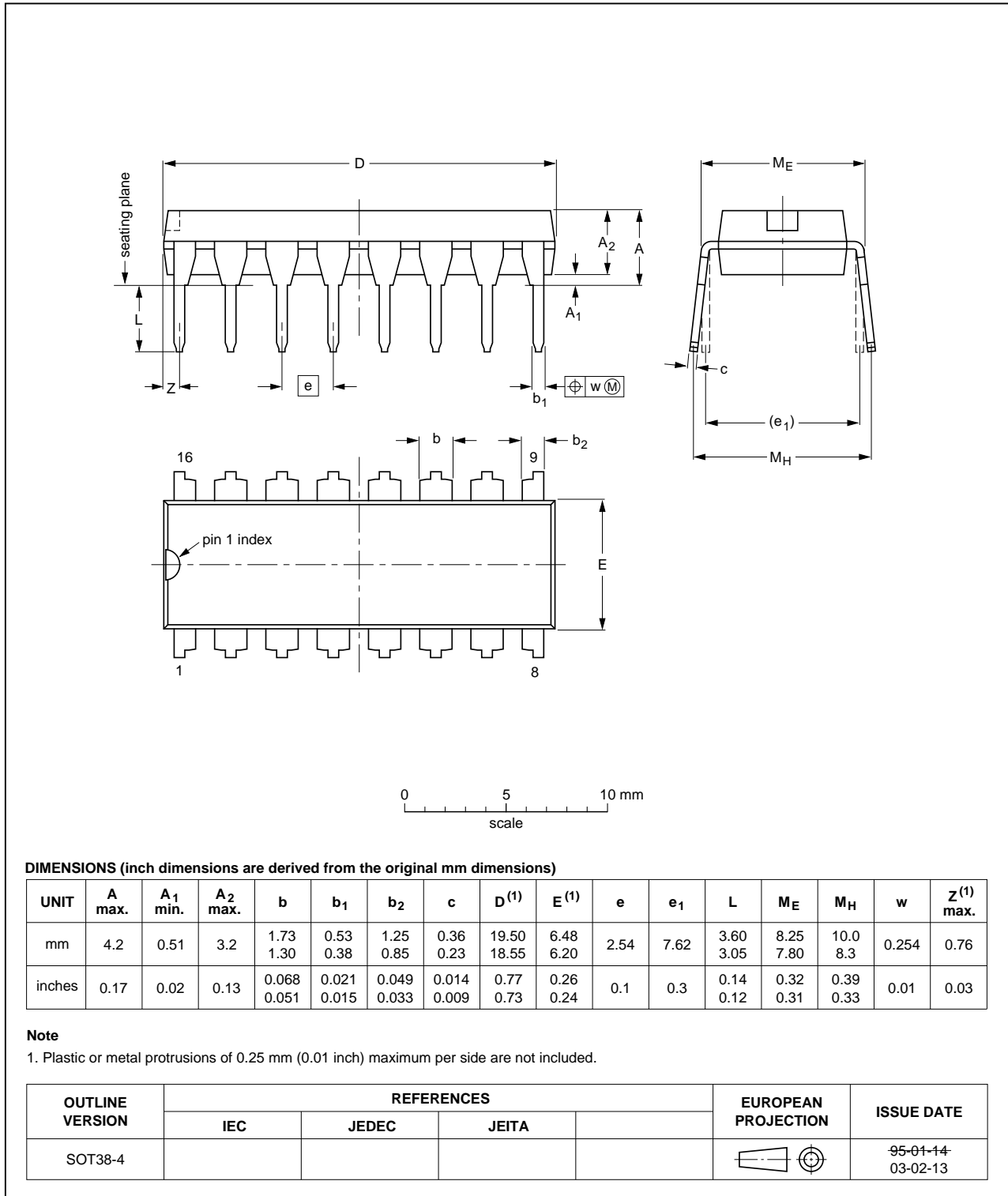


Fig 13. Package outline SOT38-4 (DIP16)

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1

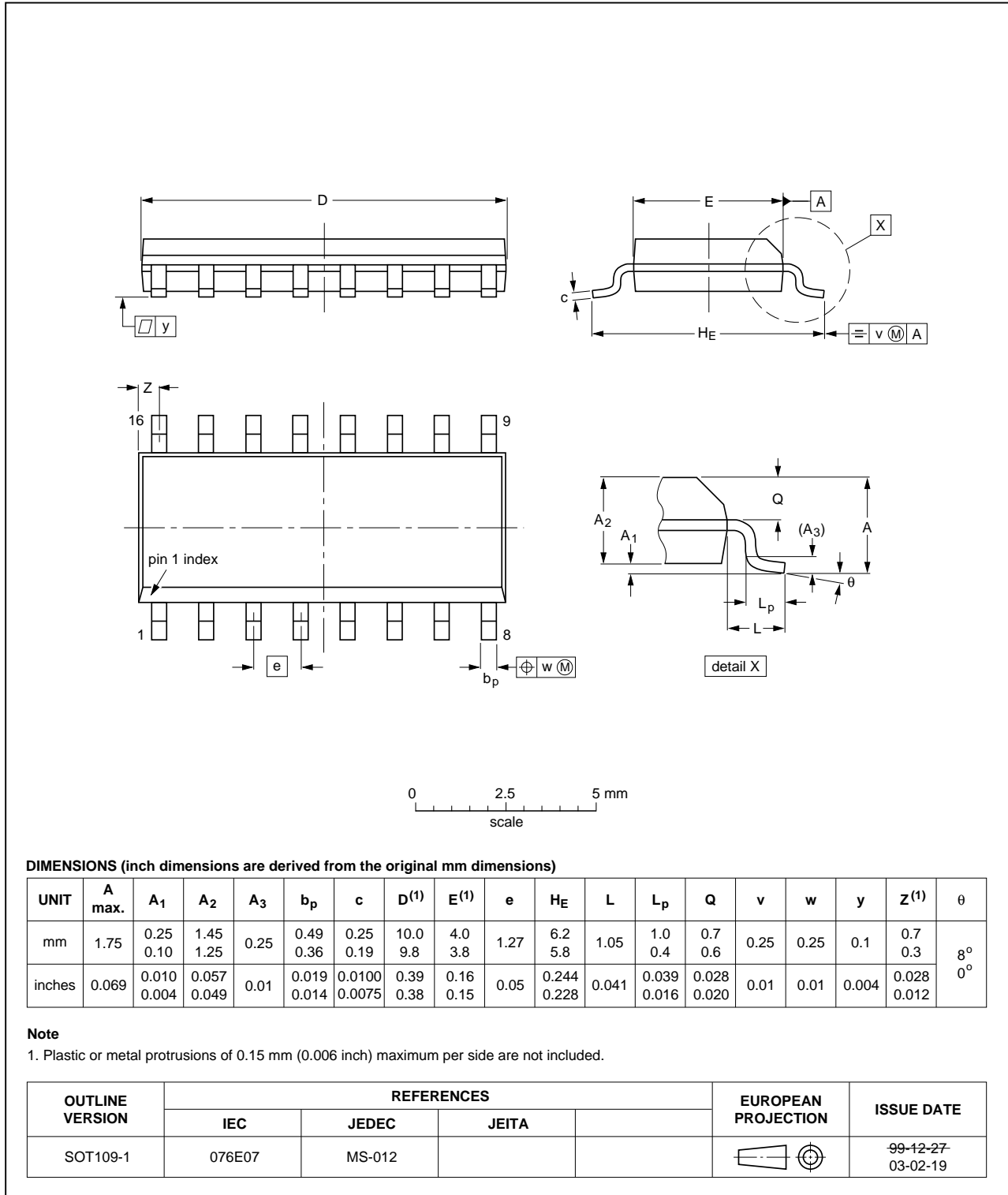


Fig 14. Package outline SOT109-1 (SO16)

SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1

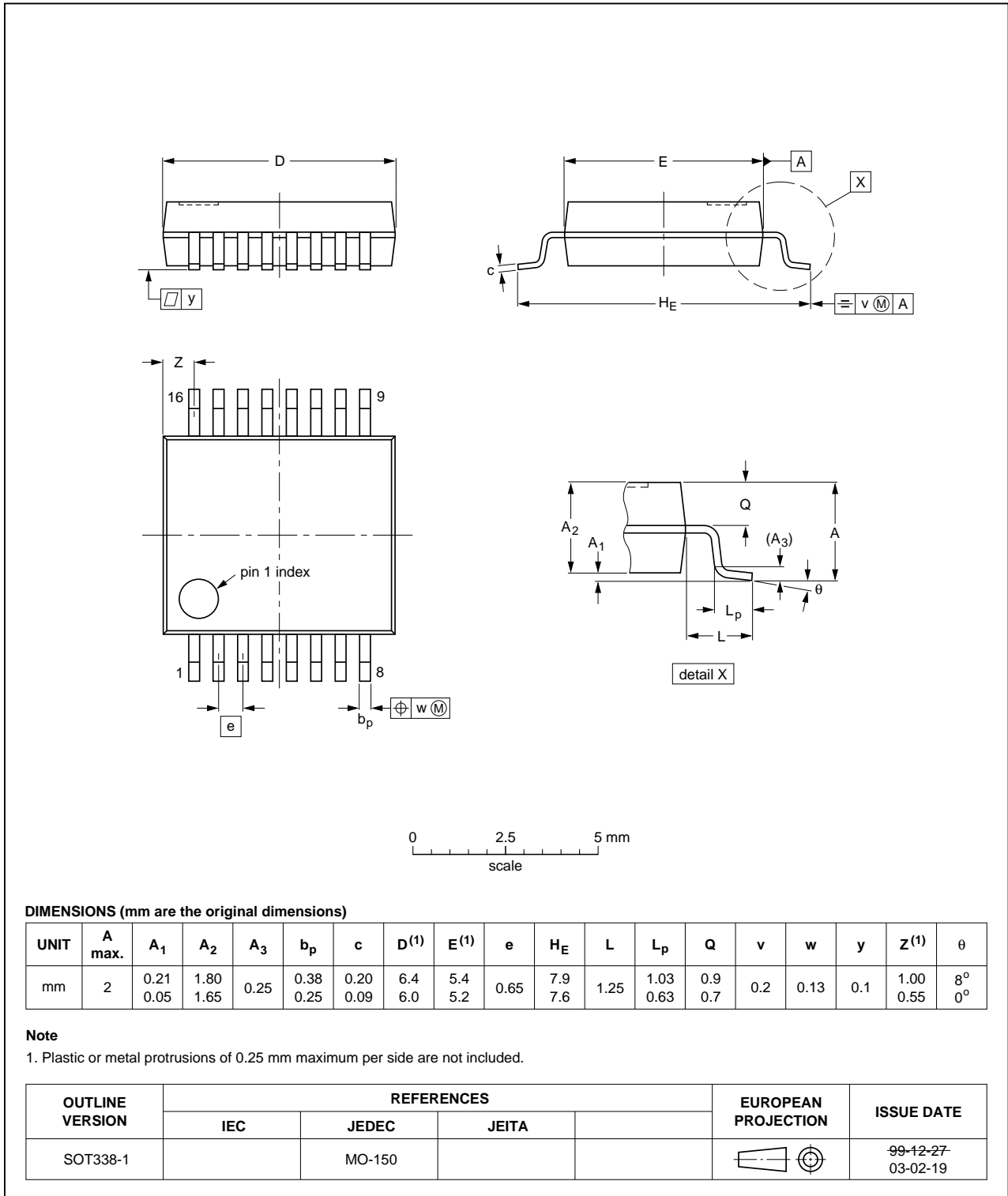


Fig 15. Package outline SOT338-1 (SSOP16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1

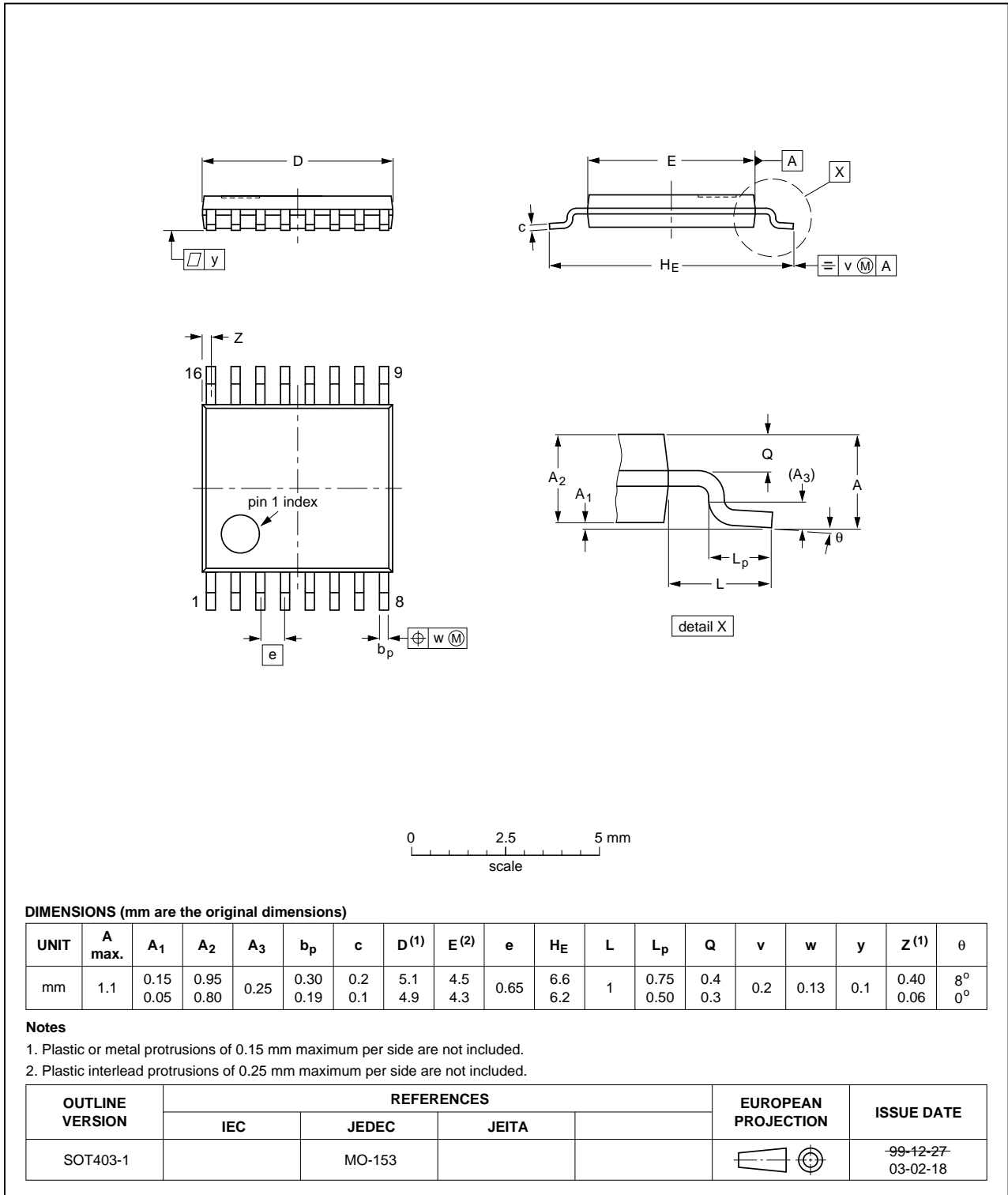


Fig 16. Package outline SOT403-1 (TSSOP16)

14. Abbreviations

Table 10. Abbreviations

| Acronym | Description |
|---------|---|
| CMOS | Complementary Metal Oxide Semiconductor |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MM | Machine Model |

15. Revision history

Table 11. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------------|--|-----------------------|---------------|----------------------|
| 74HC_HCT4094 v.5 | 20120628 | Product data sheet | - | 74HC_HCT4094 v.4 |
| Modifications: | <ul style="list-style-type: none"> V_X and V_Y measurement points added to Table 8. | | | |
| 74HC_HCT4094 v.4 | 20111219 | Product data sheet | - | 74HC_HCT4094 v.3 |
| Modifications: | <ul style="list-style-type: none"> Legal pages updated. | | | |
| 74HC_HCT4094 v.3 | 20110214 | Product data sheet | - | 74HC_HCT4094_CNV v.2 |
| 74HC_HCT4094_CNV v.2 | 19970901 | Product specification | - | - |

16. Legal information

16.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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